

High-voltage Switching Transistor (Power Supply) (120V, 7A)

2SC4849

●Features

- 1) Low saturation voltage, typically $V_{CE(sat)} = 0.17$ at $I_C / I_E = 5A / 0.5A$.
- 2) High switching speed, typically $t_f = 0.17 \mu s$ at $I_C = 5A$.
- 3) Wide SOA. (safe operating area)

●Packaging specifications and hFE

Type	2SC4849
Package	TO-220FP
hFE	E
Code	—
Basic ordering unit (pieces)	500

●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V_{CBO}	250	V
Collector-emitter voltage	V_{CEO}	120	V
Emitter-base voltage	V_{EBO}	12	V
Collector current	I_C	7	A
		15	A ($t = 100ms$)
Collector power dissipation	P_C	2	W
		30	W ($T_c = 25^\circ C$)
Junction temperature	T_J	150	°C
Storage temperature	T_{stg}	-55~+150	°C

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-emitter breakdown voltage	$V_{CEX(SUS)}$	125	—	—	V	$I_{CP} = 8A$, $I_{E1} = -I_{E2} = 0.5A$, $I_C = 5A$, $L = 200 \mu H$ clamped
Collector cutoff current	I_{CBO}	—	—	10	μA	$V_{CB} = 100V$
Collector cutoff current	I_{EBO}	—	—	10	μA	$V_{EB} = 12V$
Collector-emitter saturation voltage	$V_{CE(sat)}$	—	—	0.6	V	$I_C / I_E = 5A / 0.5A$
Base-emitter saturation voltage	$V_{BE(sat)}$	—	—	1.2	V	$I_C / I_E = 5A / 0.5A$
DC current transfer ratio	hFE	100	—	200	—	$V_{CE} / I_C = 5V / 3A$
Transition frequency	f_T	—	20	—	MHz	$V_{CE} = 10V$, $I_E = -0.5A$
Output capacitance	C_{ob}	—	150	—	pF	$V_{CB} = 10V$, $I_E = 0A$, $f = 1MHz$
Turn-on time	t_{on}	—	—	0.5	μs	$I_C = 5A$, $R_L = 10 \Omega$
Storage time	t_{stg}	—	—	2.5	μs	$I_{E1} = -I_{E2} = 0.5A$
Fall time	t_f	—	—	0.5	μs	$V_{CC} = 50V$
Collector cutoff current	I_{CEO}	—	—	2	mA	$V_{CE} = 100V$, $T_a = 125^\circ C$

(94L-712-C342)

Medium Power Transistor (Chroma Output) (300V, 0.1A)

2SC5147

●Features

- 1) High breakdown voltage. ($BV_{CEO} = 300V$)
- 2) Low collector output capacitance. (Typ. 3pF at $V_{CB} = 30V$)
- 3) Wide SOA. (safe operating area)
- 4) Ideal for color TV chroma output and amplification of video signals.

●Packaging specifications and hFE

Type	2SC5147
Package	TO-220FN
hFE	DE
Code	—
Basic ordering unit (pieces)	500

●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V_{CBO}	300	V
Collector-emitter voltage	V_{CEO}	300	V
Emitter-base voltage	V_{EBO}	5	V
Collector current	I_C	100	mA (DC)
Collector power dissipation	P_C	2	W
		10	W ($T_c = 25^\circ C$)
Junction temperature	T_J	150	°C
Storage temperature	T_{stg}	-55~+150	°C

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV_{CBO}	300	—	—	V	$I_C = 50 \mu A$
Collector-emitter breakdown voltage	BV_{CEO}	300	—	—	V	$I_C = 100 \mu A$
Emitter-base breakdown voltage	BV_{EBO}	5	—	—	V	$I_E = 50 \mu A$
Collector cutoff current	I_{CBO}	—	—	0.5	μA	$V_{CB} = 200V$
Emitter cutoff current	I_{EBO}	—	—	0.5	μA	$V_{EB} = 4V$
Collector-emitter saturation voltage	$V_{CE(sat)}$	—	0.2	1	V	$I_C / I_E = 50mA / 5mA$ *
DC current transfer ratio	hFE	60	—	200	—	$V_{CE} / I_C = 10V / 10mA$
Transition frequency	f_T	50	100	—	MHz	$V_{CE} = 30V$, $I_E = -20mA$, $f = 30MHz$
Output capacitance	C_{ob}	—	3	—	pF	$V_{CB} = 30V$, $I_E = 0A$, $f = 1MHz$

* Measured using pulse current.

(96-736-C358)